



L8560 Sinusoidal Ringing Generation Using a PWM Input to B1

Introduction

The L8560 generates a trapezoidal waveform by injecting approximately $\pm 29 \mu\text{A}$ into capacitors FB1 and FB2. When used in this mode, the ramp of the waveform is determined by this current and the size of capacitors FB1 and FB2.

If, instead, the B1 input is pulse-width modulated (PWM) by a sinusoidally modulated signal, the output at tip and ring will be the envelope of the modulation signal which is sinusoidal. Its frequency is the same as the sinusoidal modulation signals.

From the internal scheme of the L8560, shown in Figure 1, the average current delivered to FB1 or FB2 is the following:

$$I_{\text{AVG}} = 2 \times (\text{PW} - 0.5) \times 29 \mu\text{A}$$

where PW is the average pulse width, which may vary from zero to one with respect to the center at 0.5.

Thus, the output amplitude at tip/ring is:

$$V_{\text{T/R}} (\text{tip/ring}) = 4 \times \frac{29 \mu\text{A}}{\omega \times C_{\text{FB}}} \times (\text{PW} - 0.5)$$

where $V_{\text{T/R}}$ = the amplitude at tip/ring,

$$\omega = 2 \times \pi \times \text{ringing frequency},$$

$$C_{\text{FB}} = C_{\text{FB1}} = C_{\text{FB2}},$$

PW = the amplitude of PWM.

For example, if $C_{\text{FB1}} = C_{\text{FB2}} = 0.0033 \mu\text{F}$, $(\text{PW} - 0.5) = 0.46$ (27% to 73% modulation), $\omega = 2 \times \pi \times 20 \text{ Hz}$,

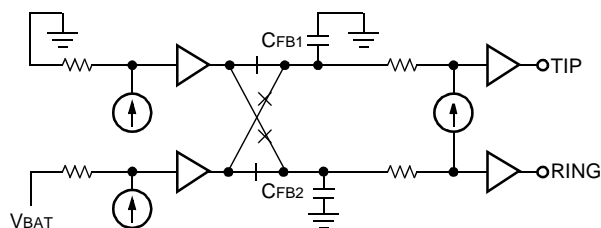
then:

$$V_{\text{T/R}} = 128 \text{ Vp-p} (45 \text{ Vrms}).$$

Design Considerations

1. Although the PWM frequency can be over a wide range, e.g., 5 kHz to 100 kHz for a normal 20 Hz ringing frequency, the normal range is expected to be 10 kHz to 20 kHz.
2. A certain design will be useful only for a given frequency. If other ringing frequencies are required, the modulation frequency and the PWM amplitude should be varied to maintain a constant gain.
3. The gain from B1 input to tip/ring output, which will result in amplitude of the voltage at tip/ring, is dependent on the capacitor value and the value of the $29 \mu\text{A}$ current source. When amplitude of the voltage at tip/ring exceeds $|V_{\text{BAT}}| - V_{\text{OH}}$, where V_{OH} is the overhead of L8560 at ringing mode (about 2 V), it starts clipping. Small amounts (less than 4 V) of clipping will result in larger (undesirable) total harmonic distortion (THD). To keep THD within a reasonable range, $\leq 5\%$, while still approaching a large output voltage at tip/ring, i.e., 45 Vrms or above, the amount of clipping must be limited. As discussed later in this document, one may have to design at the edge of clipping. That means variation may cause clipping. To ensure accuracy and minimize variation of C_{FB1} and C_{FB2} capacitors, tie them $\pm 2\%$. The internal current source ($29 \mu\text{A}$) is about $\pm 8\%$ accurate.
4. The accuracy requirement on the capacitors could be reduced by introducing a high-accuracy resistor across FB1 and FB2. But any dc offset, or any pulse-width offset, will result in clipping whenever the amplitude plus the sine-wave offset exceed the supply voltage. While in capacitor mode, offset will cause drift from side to side and will not cause clipping until the overall magnitude exceeds the supply voltage. It is recommended that precision capacitors be used for C_{FB1} and C_{FB2} in this application.
5. On the other hand, as long as the THD is still within a good range, we can make use of the clipping to absorb some amount of variations, thus allowing maximum possible voltage out of the SLIC by designing the normal output voltage right at the edge of clipping, rather than designing the minimal output voltage at the edge of clipping (to avoid any clipping).

Design Considerations (continued)

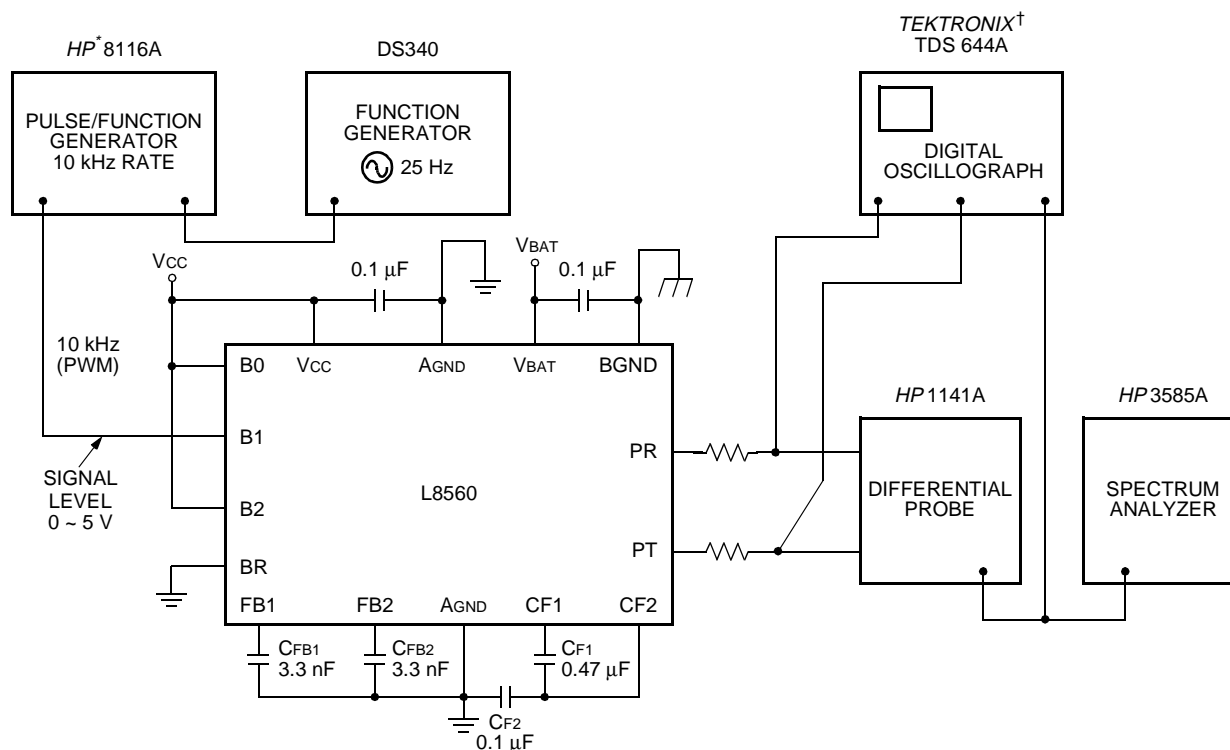


5-6388a (F)

Figure 1. L8560 Internal Scheme

Applications

Figure 2 shows the lab evaluation connections, and Figures 3—6 show the conditions where $V_{BAT} = -65.0$ V, $V_{CC} = -5.0$ V, $C_{FB1} = C_{FB2} = 0.0033$ μ F, $V_{T/R} = 43.7$ Vrms, and $T_{HD} = 1.79\%$. The output from the digital oscillograph in Figure 2 is the source for the data shown in Figures 3—5. The output from the spectrum analyzer shown in Figure 2 is the source for the data shown in Figure 6.



5-6448(F)

* HP is a registered trademark of Hewlett-Packard Company.

† Tektronix is a registered trademark of Tektronix, Inc.

Figure 2. L8560 Test Connection

Applications (continued)

Figure 3 shows the sinusoidal source output from DS340.

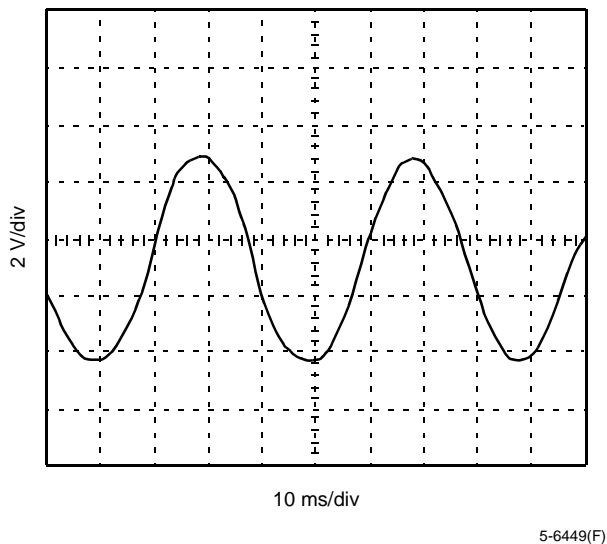


Figure 3. Sinusoidal Source from DS340

Figure 5 shows the differential output (attenuated by 100).

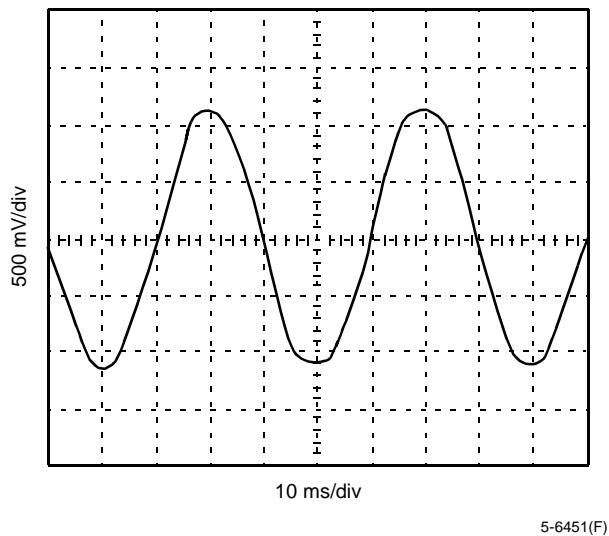


Figure 5. Differential Output (Attenuated by 100)

Figure 4 shows the output at tip and ring.

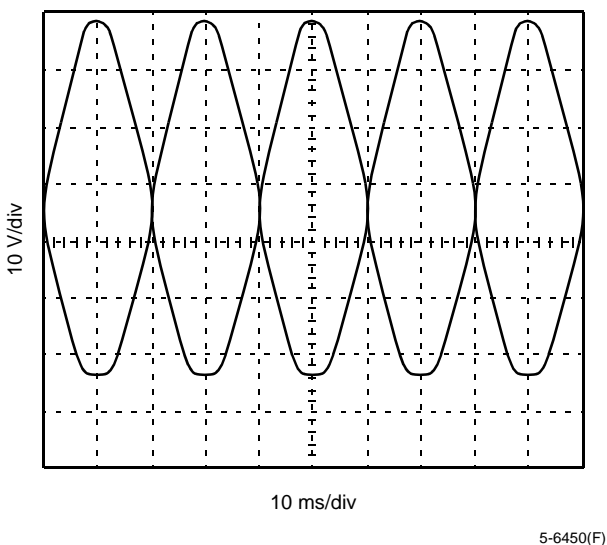


Figure 4. Tip and Ring Output

Figure 6 shows the spectrum of the differential signal.

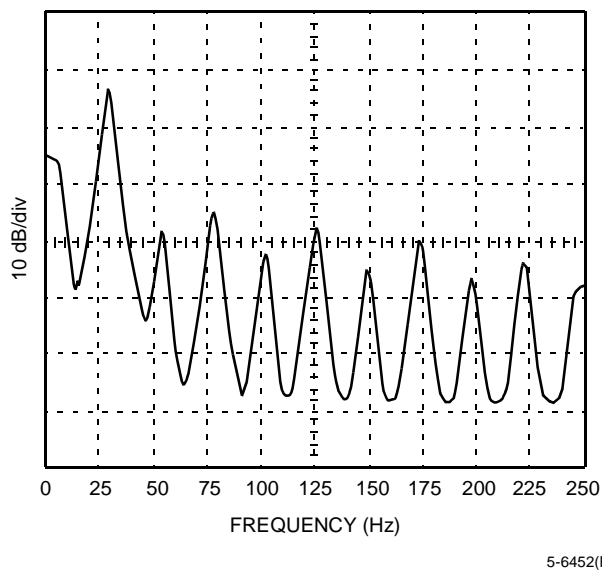


Figure 6. Differential Signal Spectrum

Applications (continued)

Normally, the amplitude of the ringing signal at the handset needs to be 40 Vrms or above. For short loop applications, 45 Vrms is desirable at tip/ring at open loop condition, or about $(45 \times 1.414 \times 2) = 126$ Vp-p.

Assume that the absolute accuracy of the C_{FB1} and C_{FB2} capacitors is at $\pm 2\%$ accuracy. Since the internal 29 μA current source is at about $\pm 8\%$ accuracy, the combination of the variation can be estimated as:

$$\sqrt{2\%^2 + 8\%^2} = 8.25\%$$

Now the resulting Vp-p at tip/ring needs to be $126 \text{ V} \times 1.0825 = 136 \text{ V}$, and the following equation represents PW.

$$136 = 4 \times \frac{29 \mu A}{2 \times 3.1415 \times \text{freq (Hz)} \times 3.3 \text{ nF}} \times (PW - 0.5)$$

Assume frequency = 25 Hz, $(PW - 0.5) = 0.60$ (means 20% to 80% modulation).

Lab evaluation experience shows that $V_{BAT(\min)} = (136/2) = 68 \text{ V}$ may keep the THD within 5% for the above case.

The maximum possible $V_{BAT(\max)} = 70 \text{ V}$ as the device is rated up to 70 V.

For additional information, contact your Microelectronics Group Account Manager or the following:

INTERNET: <http://www.lucent.com/micro>

E-MAIL: docmaster@micro.lucent.com

N. AMERICA: Microelectronics Group, Lucent Technologies Inc., 555 Union Boulevard, Room 30L-15P-BA, Allentown, PA 18103

1-800-372-2447, FAX 610-712-4106 (In CANADA: **1-800-553-2448**, FAX 610-712-4106)

ASIA PACIFIC: Microelectronics Group, Lucent Technologies Singapore Pte. Ltd., 77 Science Park Drive, #03-18 Cintech III, Singapore 118256

Tel. (65) 778 8833, FAX (65) 777 7495

CHINA: Microelectronics Group, Lucent Technologies (China) Co., Ltd., A-F2, 23/F, Zao Fong Universe Building, 1800 Zhong Shan Xi Road, Shanghai 200233 P. R. China **Tel. (86) 21 6440 0468, ext. 316**, FAX (86) 21 6440 0652

JAPAN: Microelectronics Group, Lucent Technologies Japan Ltd., 7-18, Higashi-Gotanda 2-chome, Shinagawa-ku, Tokyo 141, Japan

Tel. (81) 3 5421 1600, FAX (81) 3 5421 1700

EUROPE: Data Requests: MICROELECTRONICS GROUP DATALINE: **Tel. (44) 1189 324 299**, FAX (44) 1189 328 148

Technical Inquiries: GERMANY: **(49) 89 95086 0** (Munich), UNITED KINGDOM: **(44) 1344 865 900** (Bracknell),

FRANCE: **(33) 1 48 83 68 00** (Paris), SWEDEN: **(46) 8 600 7070** (Stockholm), FINLAND: **(358) 9 4354 2800** (Helsinki),

ITALY: **(39) 2 6608131** (Milan), SPAIN: **(34) 1 807 1441** (Madrid)

Lucent Technologies Inc. reserves the right to make changes to the product(s) or information contained herein without notice. No liability is assumed as a result of their use or application. No rights under any patent accompany the sale of any such product(s) or information.

